**Product data sheet** 

## 1. General description

Silicon Carbide Schottky diode in a 2-lead TO247-2L plastic package, designed for high frequency switched-mode power supplies.





#### 2. Features and benefits

- · Extremely fast reverse recovery time
- Low figure of merit (Q<sub>C</sub>\*V<sub>F</sub>)
- · Highly stable switching performance
- Superior in efficiency to Silicon Diode alternatives
- · Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

## 3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

#### 4. Quick reference data

### Table 1. Quick reference data

iable I. Q	uick reference data						
Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
$V_{RRM}$	repetitive peak reverse voltage			12	200		V
$I_{F(AV)}$	average forward current	$\delta$ = 0.5; square-wave pulse; T <sub>mb</sub> ≤ 108 °C; Fig. 1; Fig. 2; Fig. 3	20		А		
T <sub>j</sub>	junction temperature		175		°C		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>		-	1.5	1.8	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>		-	2.1	2.5	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>		-	2.25	2.8	V
Dynamic	characteristics		'			,	
Q <sub>r</sub>	recovered charge	$I_F = 20 \text{ A}$ ; $dI_F/dt = 500 \text{ A/}\mu\text{s}$ ; $V_R = 400 \text{ V}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7		-	39	-	nC
	1	I					

# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		к IД л
2	Α	anode		K ——— A 001aaa020
mb	mb	mounting base; connected to cathode	K A TO247-2L	

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC2D201200W	TO247-2L	WNSC2D201200WQ	Tube	30	TO247L-2L	10-Nov-2020

## 7. Marking

#### **Table 4. Marking codes**

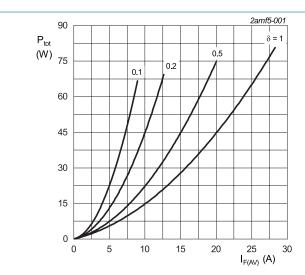
Type number	Marking codes
WNSC2D201200W	WNSC2D 201200W

# 8. Limiting values

**Table 5. Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		1200	V
$V_{RWM}$	crest working reverse voltage		1200	V
$V_R$	reverse voltage	DC	1200	V
I <sub>F(AV)</sub>	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 108$ °C; Fig. 1; Fig. 2; Fig. 3	20	А
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5; t <sub>p</sub> = 25 μs; T <sub>mb</sub> ≤ 108 °C; square-wave pulse	40	А
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	125	Α
	forward current	t <sub>p</sub> = 10 μs; T <sub>j(init)</sub> = 25 °C; square-wave pulse	1150	Α
l <sup>2</sup> t	I <sup>2</sup> t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$ ; $t_p = 10 \text{ ms}$	78	A <sup>2</sup> s
T <sub>stg</sub>	storage temperature		-55 to 175	°C
T <sub>j</sub>	junction temperature		175	°C



 $\begin{aligned} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_{o} &= 0.728 \text{ V; } R_{s} = 0.0751 \text{ }\Omega \end{aligned}$ 

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

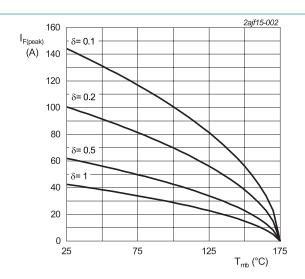
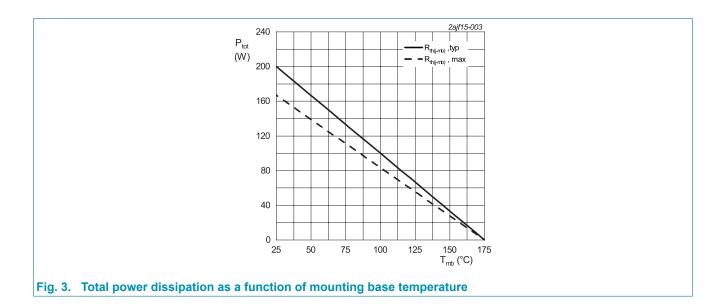


Fig. 2. Current derating as a function of mounting base temperature



### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	Fig. 4	-	0.75	0.9	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W

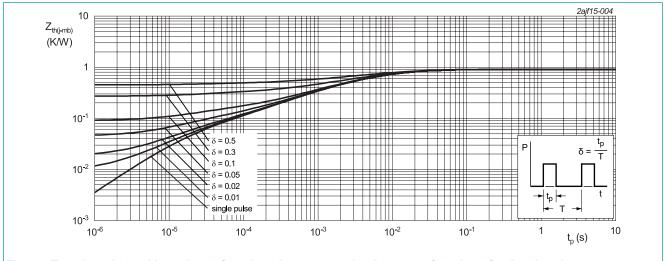
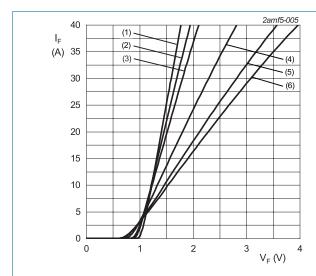


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V <sub>F</sub>	forward current	I <sub>F</sub> = 20 A; T <sub>j</sub> = 25 °C; <u>Fig. 5</u>	-	1.5	1.8	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 150 °C; <u>Fig. 5</u>	-	2.1	2.5	V
		I <sub>F</sub> = 20 A; T <sub>j</sub> = 175 °C; <u>Fig. 5</u>	-	2.25	2.8	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 1200 V; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	8	200	μA
		V <sub>R</sub> = 1200 V; T <sub>j</sub> = 175 °C; <u>Fig. 6</u>	-	90		μA
Dynamic	characteristics					
Q <sub>r</sub>	recovered charge	$I_F = 20 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 500 \text{ A/}\mu\text{s}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7	-	39	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	845	-	pF
		f = 1 MHz; V <sub>R</sub> = 400 V; T <sub>j</sub> = 25 °C	-	79	-	pF
		f = 1 MHz; V <sub>R</sub> = 800 V; T <sub>j</sub> = 25 °C	-	58	-	pF
E <sub>as</sub>	non-repetitive avalanche energy	I <sub>R</sub> = 5.3 A; L = 10 mH; T <sub>j(init)</sub> = 25 °C	140	-	-	mJ



 $V_0 = 0.728 \text{ V}; R_s = 0.0751 \Omega$ 

(1)  $T_i = -55$  °C; typical values

(2)  $T_i = 0$  °C; typical values

(3) T<sub>j</sub> = 25 °C; typical values

(4) T<sub>j</sub> = 100 °C; typical values

(5)  $T_j = 150$  °C; typical values

(6)  $T_i = 175 \,^{\circ}\text{C}$ ; typical values

Fig. 5. Forward current as a function of forward voltage; typical values

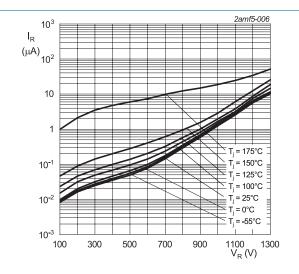


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value

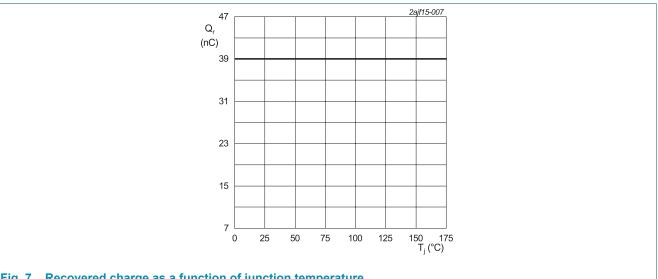
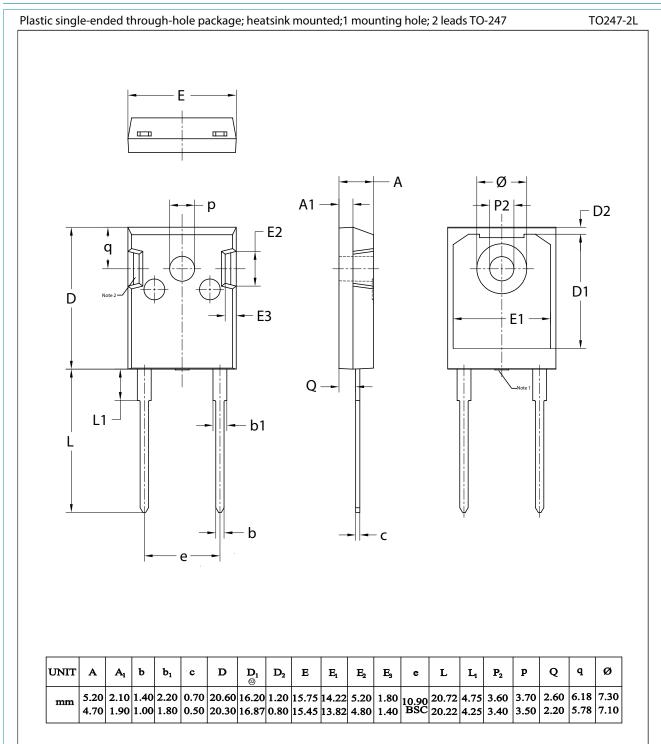


Fig. 7. Recovered charge as a function of junction temperature

# 11. Package outline



#### Note:

- 1. Mold resin protrusion max 0.127mm.
- 2. Metal exposed with Sn plating.

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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